

DIODE-THYRISTOR MODULE

MO2-(25, 40, 63, 80, 100, 125, 160, 200, 250)-12; MO2A-(25, 40, 63, 80, 100, 125, 160, 200, 250)-12 DATASHEET IN BRIEF

Diode-thyristor module with opto decoupling is designed for using in switch elements of controlled rectifiers, converters (inverters), power regulators for powerful loads of DC and AC.

OVERALL DRAWINGS

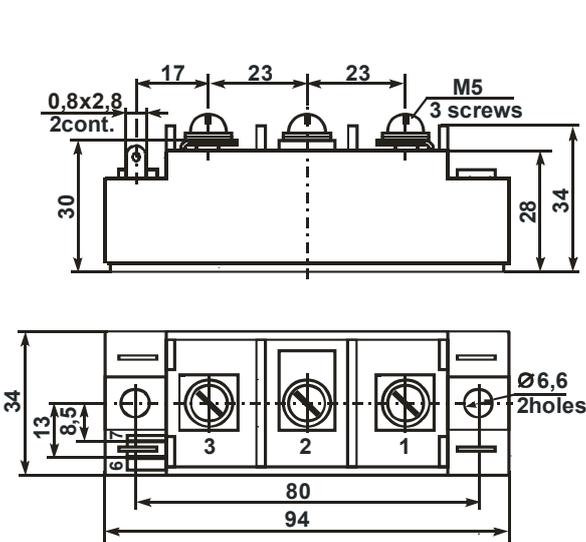


Figure 1

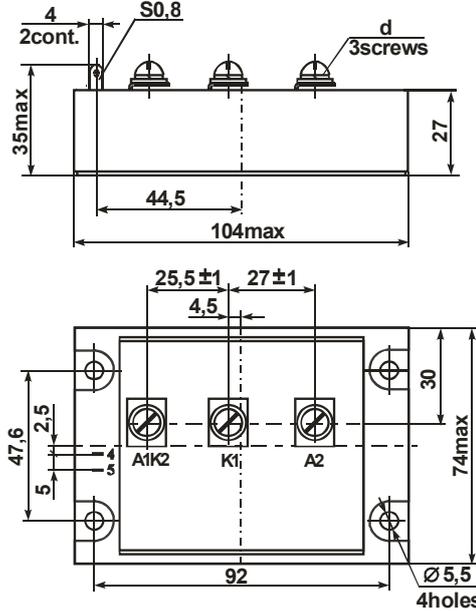


Figure 2

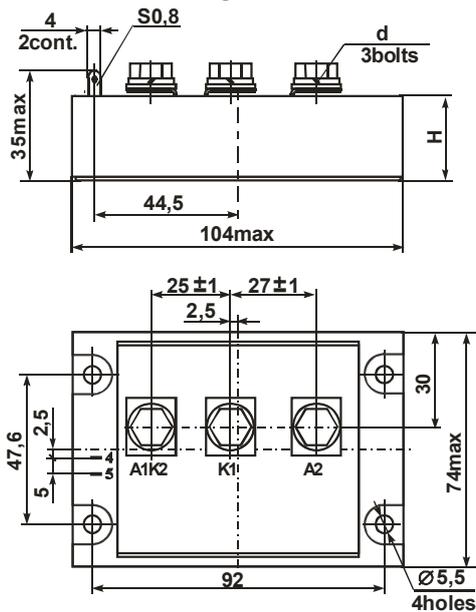


Figure 3

Product description	Figure	H, MM
MO2(A)-25-12	1, 4	-
MO2(A)-40-12	1, 4	-
MO2(A)-63-12	1, 4	-
MO2(A)-80-12	1, 4	-
MO2(A)-100-12	1, 4	-
MO2(A)-125-12	1, 4	-
MO2(A)-160-12	1, 4 or 2, 5	-
MO2(A)-200-12	3, 5	29
MO2(A)-250-12	3, 5	29

INTERNAL CONNECTION CIRCUITS

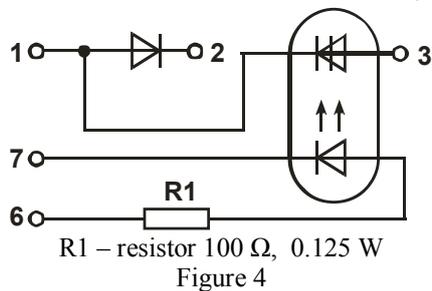


Figure 4

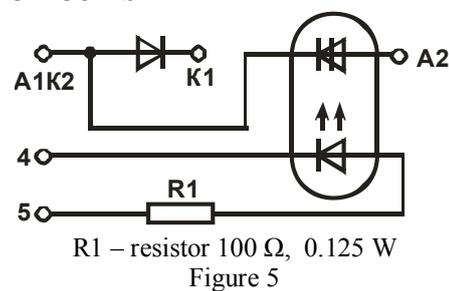


Figure 5

BASIC CHARACTERISTICS

T = 25 °C

Product name	Pulse on-state voltage/pulse DC diode current, U_{TM} , V		Off-state DC/thyristor (diode) reverse current, I_D / I_R , mA		On-state voltage on control input, U_{Gon} , V ($I_{Gon}=10$ mA)		Isolation resistance between power outputs and controlling outputs, R_{ISOL} , MΩ		Isolation resistance between power outputs and housing radiator, R_{ISOL} in-out, MΩ		Electric isolation strength at DC between radiator and power outputs, U_{ISOL} , V		Thermal transition-housing radiator resistance R_{thic} , °C/W	
													thyristor	diode
	max	I_{OUT} , A	max	U_{OUT} , V	min	max	min	U, V	min	U, V	min	t, minute	max	max
MO2-25-12	1.65	79	1.0	±1200	3.0	4.0	100	500	10	500	4000	1	0.8	1.2
MO2-40-12		126											0.7	0.9
MO2-63-12		198											0.55	0.6
MO2-80-12		251											0.45	0.5
MO2-100-12		314											0.3	0.4
MO2-125-12		393											0.25	0.3
MO2-160-12		503											0.22	0.25
MO2-200-12		628											0.19	0.21
MO2-250-12		785											0.15	0.169

Note –module characteristics values of type MO2A are identical to the characteristic values of the corresponding modules MO2

MAXIMUM PERMISSIBLE OPERATING MODES

Product name	Repetitive pulse reverse voltage/off-state, U_{RRM} / U_{DRM} , V	Average on-state current with cooler $I_{T(AV)}$, A, $T_a=85$ °C	Controlling input current corresponding to on-state, I_{Gon} , mA		Controlling pulse input current corresponding to on-state, I_{GMon} , mA		Off-state input voltage, U_{Goff} , V		On state surge current*, I_{TSM} , A	Switching voltage, U_{sw} , V		Critical rate of rise of off-state voltage, $(du_d / dt)_{cr}$, V/μs	Critical rate of rise of on-state current, $(di_T / dt)_{cr}$, A/ μs	Junction temperature, T_{VJ}^{***} , °C				
			min	max	max	t, μs	Q	min		max	max			t, ms	min	max	min	max
			max	max	min	max	max	μs		Q	min			max	max	ms	min	max
MO2-25-12	±1200	25	10	25	100	100	10	- 3.5	0.8	10	50**	840	1000	150	-40	+125		
MO2-40-12		40															200	
MO2-63-12		63															560	
MO2-80-12		80															720	
MO2-100-12		100															960	
MO2-125-12		125															1350	
MO2-160-12		160															2500	
MO2-200-12		200															4000	
MO2-250-12		250															5000	
		6000																

* to thyristor

**10 V – for modules of type MO2A (the value of remaining modes of modules types MO2A are identical with values modes of corresponding modules MO2)

***the modules are designed for operating in the equipment with using of coolers, supporting transition temperature in prescribed ranges

Precious metals are not contained

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